



IFIN

U.S.S.N. 07/632,379

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Yang et al. Group Art Unit: 2829

Serial No.: 10/632,379 Examiner: D. Farahani

Filed: 08/01/2003 In Response to Office Action
Dated: 08/30/2005

For: FIELD EFFECT TRANSISTOR (FET) DEVICE HAVING
CORRUGATED STRUCTURE AND METHOD FOR FABRICATION THEREOF

Attorney Docket No.: 67,200-377

CERTIFICATE OF MAILING OR FACSIMILE TRANSMISSION

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Randy W. Tung
Printed Name

Signature

11/30/05
Date

Please forward all correspondence to
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Request For Reconsideration

Assistant Commissioner
for Patents
P.O. Box 1450
Alexandria, Va 22313-1450

Dear Sir:

In response to an Office Action mailed 08/30/2005
please enter the following amendments and consider the following
remarks.